3.3 V Dual LVTTL/LVCMOS to Differential LVPECL **Translator**

Description

The MC100EPT22 is a dual LVTTL/LVCMOS to differential LVPECL translator. Because LVPECL (Positive ECL) levels are used only +3.3 V and ground are required. The small outline 8-lead package and the single gate of the EPT22 makes it ideal for those applications where space, performance, and low power are at a premium. Because the mature MOSAIC 5 process is used, low cost and high speed can be added to the list of features.

Features

- 420 ps Typical Propagation Delay
- Maximum Frequency = > 1.1 GHz Typical
- Operating Range: $V_{CC} = 3.0 \text{ V}$ to 3.6 V with GND = 0 V
- PNP LVTTL Inputs for Minimal Loading
- Q Output Will Default HIGH with Inputs Open
- The 100 Series Contains Temperature Compensation.
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



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SOIC-8 NB **D SUFFIX**

TSSOP-8 **DT SUFFIX** CASE 751-07 CASE 948R-02 CASE 506AA

MN SUFFIX

MARKING DIAGRAMS*







SOIC-8 NB

TSSOP-8

DFN8

Α = Assembly Location

= Wafer Lot L Υ = Year W = Work Week = Date Code M = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping† |
|-----------------|------------------------|------------------|
| MC100EPT22DG | SOIC-8 NB (Pb-Free) | 98 Units/Tube |
| MC100EPT22DR2G | SOIC-8 NB (Pb-Free) | 2500 Tape & Reel |
| MC100EPT22DTG | TSSOP-8 (Pb-Free) | 100 Tape & Reel |
| MC100EPT22DTR2G | TSSOP-8 (Pb-Free) | 2500 Tape & Reel |
| MC100EPT22MNR4G | DFN8 (Pb-Free) | 1000 Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional marking information, refer to Application Note AND8002/D.

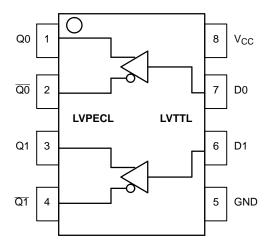


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram

Table 1. PIN DESCRIPTION

| PIN | FUNCTION |
|---------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Q0, Q1, Q0 , Q1 | LVPECL Differential Outputs |
| D0, D1 | LVTTL Inputs |
| V _{CC} | Positive Supply |
| GND | Ground |
| EP | (DFN8 only) Thermal exposed pad must be connected to a sufficient thermal conduit. Electrically connect to the most negative supply (GND) or leave unconnected, floating open. |

Table 2. ATTRIBUTES

| Characteristics | Value |
|--------------------------------------------------------------------|-------------------------------|
| Internal Input Pulldown Resistor | N/A |
| Internal Input Pullup Resistor | N/A |
| ESD Protection Human Body Model Machine Model Charged Device Model | > 4 kV > 200 V > 2 kV |
| Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1) | Pb-Free Pkg |
| SOIC-8 NB TSSOP-8 DFN8 | Level 1 Level 3 Level 1 |
| Flammability Rating Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in |
| Transistor Count | 164 Devices |
| Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test | |

^{1.} For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

| Symbol | Parameter | Condition 1 | Condition 2 | Rating | Unit |
|-------------------|------------------------------------------|---------------------|------------------------|-------------|------|
| V _{CC} | Power Supply | GND = 0 V | | 6 | V |
| VI | Input Voltage | GND = 0 V | $V_{I} \leq V_{CC}$ | 6 to 0 | V |
| l _{out} | Output Current | Continuous Surge | | 50 100 | mA |
| T _A | Operating Temperature Range | | | -40 to +85 | °C |
| T _{stg} | Storage Temperature Range | | | -65 to +150 | °C |
| θ_{JA} | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | SOIC-8 NB SOIC-8 NB | 190 130 | °C/W |
| $\theta_{\sf JC}$ | Thermal Resistance (Junction-to-Case) | Standard Board | SOIC-8 NB | 41 to 44 | °C/W |
| θ_{JA} | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | TSSOP-8 TSSOP-8 | 185 140 | °C/W |
| $\theta_{\sf JC}$ | Thermal Resistance (Junction-to-Case) | Standard Board | TSSOP-8 | 41 to 44 | °C/W |
| $\theta_{\sf JA}$ | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | DFN8 DFN8 | 129 84 | °C/W |
| T _{sol} | Wave Solder (Pb-Free) | | | 265 | °C |
| $\theta_{\sf JC}$ | Thermal Resistance (Junction-to-Case) | (Note 1) | DFN8 | 35 to 40 | °C/W |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 4. TTL INPUT DC CHARACTERISTICS ($V_{CC} = 3.3 \text{ V}$, GND = 0 V, $T_A = -40 ^{\circ}\text{C}$ to $85 ^{\circ}\text{C}$)

| Symbol | Characteristic | Condition | Min | Тур | Max | Unit |
|------------------|------------------------|--------------------------|-----|-----|------|------|
| I _{IH} | Input HIGH Current | V _{IN} = 2.7 V | | | 20 | μΑ |
| I _{IHH} | Input HIGH Current MAX | $V_{IN} = V_{CC}$ | | | 100 | μΑ |
| I _{IL} | Input LOW Current | V _{IN} = 0.5 V | | | -0.6 | mA |
| V_{IK} | Input Clamp Voltage | I _{IN} = -18 mA | | | -1.0 | V |
| V _{IH} | Input HIGH Voltage | | 2.0 | | | V |
| V_{IL} | Input LOW Voltage | | | | 0.8 | V |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

Table 5. PECL OUTPUT DC CHARACTERISTICS ($V_{CC} = 3.3 \text{ V}$, GND = 0.0 V (Note 1))

| | | −40°C | | 25°C | | | 85°C | | | | |
|-----------------|------------------------------|-------|------|------|------|------|------|------|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| I _{CC} | Power Supply Current | 32 | 43 | 55 | 35 | 45 | 60 | 37 | 46 | 62 | mA |
| V _{OH} | Output HIGH Voltage (Note 2) | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | mV |
| V_{OL} | Output LOW Voltage (Note 2) | 1355 | 1480 | 1605 | 1355 | 1480 | 1605 | 1355 | 1480 | 1605 | mV |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Output parameters vary 1:1 with V_{CC} . 2. All loading with 50 Ω to V_{CC} 2.0 V.

^{1.} JEDEC standard multilayer board - 2S2P (2 signal, 2 power)

Table 6. AC CHARACTERISTICS ($V_{CC} = 3.0 \text{ V}$ to 3.6 V, GND = 0.0 V (Note 1))

| | | | -40°C | | | 25°C | | | 85°C | | |
|----------------------------------------|-----------------------------------------------------------------------------------------|-----|-----------|------------|-----|--------------|------------|-----|-----------|------------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| f _{max} | Maximum Frequency (Figure 2) | 0.8 | 1.1 | | 0.8 | 1.1 | | 0.8 | 1.1 | | GHz |
| t _{PLH} , t _{PHL} | Propagation Delay to Output Differential | 250 | 400 | 650 | 250 | 420 | 675 | 300 | 500 | 700 | ps |
| t _{skew} | Within–Device Skew (Note 2) Device-to-Device Skew (Note 3) | | 50 200 | 100 400 | | 50 200 | 100 425 | | 50 200 | 100 400 | ps |
| t _{JITTER} | Random Clock Jitter (Figure 2) | | 0.2 | < 1 | | 0.2 | < 1 | | 0.2 | < 1 | ps |
| t _{JIT(Φ)} | Additive Phase RMS Jitter Integration Range 12 kHz to 20 MHz 25 MHz 156.25 MHz | | | | | 0.05 0.16 | | | | | ps |
| t _r t _f | Output Rise/Fall Times Q, Q (20%–80%) | 50 | 110 | 200 | 60 | 120 | 220 | 70 | 140 | 250 | ps |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Measured using a 2.4 V source, 50% duty cycle clock source. All loading with 50 Ω to V_{CC} 2.0 V.
- 2. Skew is measured between outputs under identical transitions and conditions on any one device.
- 3. Device-to-Device Skew for identical transitions at identical V_{CC} levels.

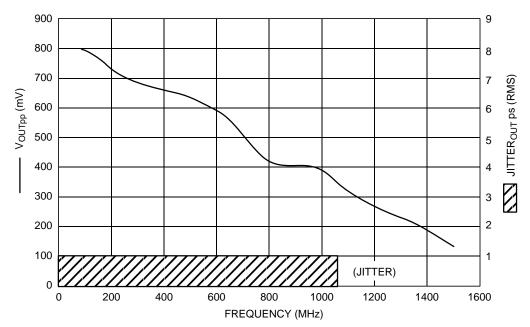


Figure 2. F_{max}/Jitter

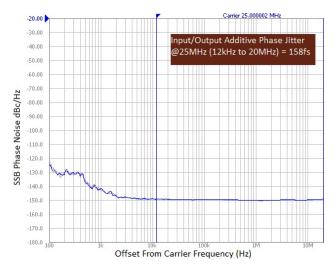


Figure 3. Typical Phase Noise Plot at f_{carrier} = 25 MHz

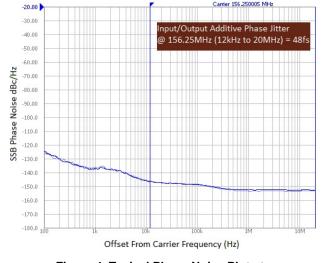


Figure 4. Typical Phase Noise Plot at $f_{carrier} = 156.25 \text{ MHz}$

The above phase noise plots captured using Agilent E5052A show additive phase noise of the MC100EPT22 device at frequencies 25 MHz and 156.25 MHz respectively at an operating voltage of 3.3 V in room temperature. The RMS Phase Jitter contributed by the device (integrated

between 12 kHz and 20 MHz; as shown in the shaded region of the plot) at each of the frequencies is 158 fs and 48 fs respectively. The input source used for the phase noise measurements is Agilent E8663B.

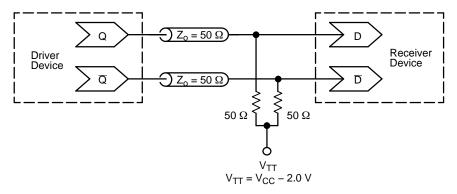


Figure 5. Typical Termination for Output Driver and Device Evaluation (See Application Note <u>AND8020/D</u> – Termination of ECL Logic Devices)

Resource Reference of Application Notes

AN1405/D – ECL Clock Distribution Techniques

AN1406/D – Designing with PECL (ECL at +5.0 V)

AN1503/D – ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family
AN1568/D - Interfacing Between LVDS and ECL

AN1672/D - The ECL Translator Guide

AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

AND8020/D - Termination of ECL Logic Devices

AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices

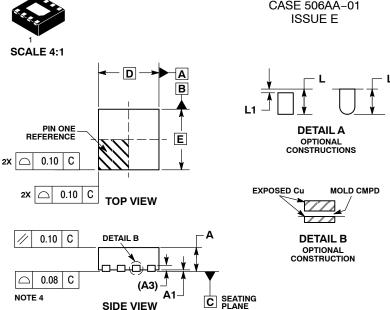
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DETAIL A

е

- D2 →

BOTTOM VIEW



0.10 C

Ф

AB

0.05 C NOTE 3



DATE 22 JAN 2010

NOTES

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994 . CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

| l | MILLIMETERS | | | | |
|-----|-------------|--------|--|--|--|
| | MILLIN | IETERS | | | |
| DIM | MIN | MAX | | | |
| Α | 0.80 | 1.00 | | | |
| A1 | 0.00 | 0.05 | | | |
| A3 | 0.20 | REF | | | |
| b | 0.20 | 0.30 | | | |
| D | 2.00 | BSC | | | |
| D2 | 1.10 | 1.30 | | | |
| E | 2.00 BSC | | | | |
| E2 | 0.70 0.90 | | | | |
| е | 0.50 BSC | | | | |
| K | 0.30 | REF | | | |
| L | 0.25 | 0.35 | | | |
| L1 | | 0.10 | | | |

GENERIC MARKING DIAGRAM*



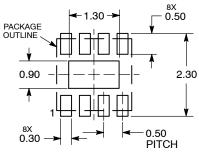
XX = Specific Device Code

= Date Code = Pb-Free Device

*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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|------------------|---------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------|--|--|
| DESCRIPTION: | DFN8, 2.0X2.0, 0.5MM PITO | CH | PAGE 1 OF 1 | | |

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SOIC-8 NB CASE 751-07 **ISSUE AK**

DATE 16 FEB 2011



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| | MILLIN | IETERS | INC | HES | |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 4.80 | 5.00 | 0.189 | 0.197 | |
| В | 3.80 | 4.00 | 0.150 | 0.157 | |
| С | 1.35 | 1.75 | 0.053 | 0.069 | |
| D | 0.33 | 0.51 | 0.013 | 0.020 | |
| G | 1.27 | 7 BSC | 0.050 BSC | | |
| Н | 0.10 | 0.25 | 0.004 | 0.010 | |
| J | 0.19 | 0.25 | 0.007 | 0.010 | |
| K | 0.40 | 1.27 | 0.016 | 0.050 | |
| М | 0 ° | 8 ° | 0 ° | 8 ° | |
| N | 0.25 | 0.50 | 0.010 | 0.020 | |
| S | 5.80 | 6.20 | 0.228 | 0.244 | |

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

= Wafer Lot = Year = Work Week

= Pb-Free Package



XXXXXX = Specific Device Code = Assembly Location Α

= Year ww = Work Week

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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SOIC-8 NB CASE 751-07 ISSUE AK

DATE 16 FEB 2011

| STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 6. EMITTER, #2 7. BASE, #1 8. EMITTER, #1 STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE STYLE 10: PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND 5. GROUND 6. PINS 2 | STYLE 3: PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1 STYLE 7: PIN 1. IMPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 | 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE 2. SOURCE |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE STYLE 10: PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND | PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 | PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE 2. SOURCE |
| PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND | PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 | PIN 1. SOURCE 2. SOURCE |
| 6. BIAS 2 7. INPUT 8. GROUND | 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1 | 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN |
| STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN | STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON | STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2 4. BASE, DIE #2 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 7. COLLECTOR, DIE #1 8. COLLECTOR, DIE #1 |
| STYLE 18: PIN 1. ANODE 2. ANODE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE | STYLE 19: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1 | STYLE 20: PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN |
| STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3. COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND | STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT | STYLE 24: PIN 1. BASE 2. EMITTER 3. COLLECTOR/ANODE 4. COLLECTOR/ANODE 5. CATHODE 6. CATHODE 7. COLLECTOR/ANODE 8. COLLECTOR/ANODE |
| STYLE 26: PIN 1. GND 2. dv/dt 3. ENABLE 4. ILIMIT 5. SOURCE 6. SOURCE 7. SOURCE 8. VCC | STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN | STYLE 28: PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V_MON 6. VBULK 7. VBULK 8. VIN |
| STYLE 30: PIN 1. DRAIN 1 2. DRAIN 1 3. GATE 2 4. SOURCE 2 5. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 8. GATE 1 | | |
| | PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE 8. CATHODE 8. CATHODE 8. CATHODE 8. CATHODE 9. COMMON CATHODE/VCC 9. COMMON CATHODE/VCC 1. I/O LINE 1 2. COMMON CATHODE/VCC 1. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 5 8. COMMON ANODE/GND 8. COMMON ANODE/GND 8. COMMON ANODE/GND 8. COMMON ANODE/GND 8. I/O LINE 5 8. COMMON ANODE/GND 8. SOURCE 9. II. ILIMIT 9. SOURCE 1. SOURCE 1. SOURCE 1. SOURCE 2. SOURCE 1 2. SOURCE 1 3. GATE 2 4. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 | PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. N-DRAIN 7. CATHODE, COMMON 8. N-DRAIN 8. CATHODE, COMMON 8. CATHODE 9IN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 4. GATE 2 5. DRAIN 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1 8. COMMON CATHODE/VCC 1. COMMON CATHODE/VCC 1. COMMON CATHODE/VCC 1. (/O LINE 1 2. COMMON CATHODE/VCC 1. (/O LINE 3 5. COMMON ANODE/GND 6. (/O LINE 4 7. (/O LINE 5 8. COMMON ANODE/GND 8. LINE 2 OUT 9. COMMON ANODE/GND 8. LINE 1 OUT STYLE 26: PIN 1. GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 27: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 28: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. COMMON ANODE/GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. COMM |

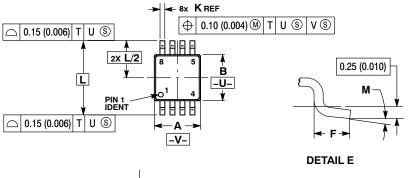
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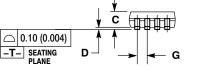
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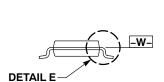


TSSOP 8 CASE 948R-02 ISSUE A

DATE 04/07/2000







- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH. OR GATE BURRS SHALL NOT EXCEED 0.15
- (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
 6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 2.90 | 3.10 | 0.114 | 0.122 |
| В | 2.90 | 3.10 | 0.114 | 0.122 |
| С | 0.80 | 1.10 | 0.031 | 0.043 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.40 | 0.70 | 0.016 | 0.028 |
| G | 0.65 BSC | | 0.026 BSC | |
| K | 0.25 | 0.40 | 0.010 | 0.016 |
| L | 4.90 BSC | | 0.193 BSC | |
| M | ٥° | 6 ° | ٥° | 6° |

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